NPN Epitaxial Planar Silicon Transistor

2SC4491



L Load (Various Drivers) Switching Applications

Applications

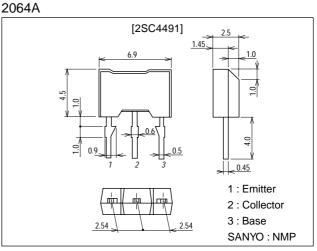
• Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

Features

- · Darlington connection.
- \cdot On-chip Zener diode of 60±10V between collector and base.
- · Uniformity in collector-to-base voltage.
- · High DC current gain.
- \cdot Wide ASO.
- · Large inductive load handling capability.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		50*	V
Collector-to-Emitter Voltage	V _{CEO}		50*	V
Emitter-to-Base Voltage	V _{EBO}		6	V
Collector Current	IC		1.2	A
Collector Current (Pulse)	I _{CP}		2.5	A
Collector Dissipation	PC		1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

* : On-chip Zener diode (60±10V)

Electrical Characteristics at Ta = 25°C

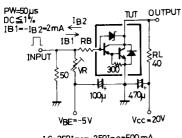
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	I _{CBO}	V _{CB} =40V, I _E =0			10	μA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μA
DC Current Gain	h _{FE}	$V_{CE}=5V, I_{C}=500$ mA	1000	5000		
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA, I _B =2mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =500mA, I _B =2mA			2.0	V
Inductiv Load Handling Capability	Es/b	L=100mH, R _{BE} =100Ω	15			mJ

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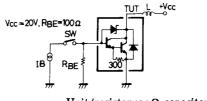
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =100μA, I _E =0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	50	60	70	V
Turn-on Time	ton	See specified Test Circuit.		0.2		μs
Storage Time	^t stg	See specified Test Circuit.		2.2		μs
Fall Time	t _f	See specified Test Circuit.		0.4		μs

Switching Time Test Circuit

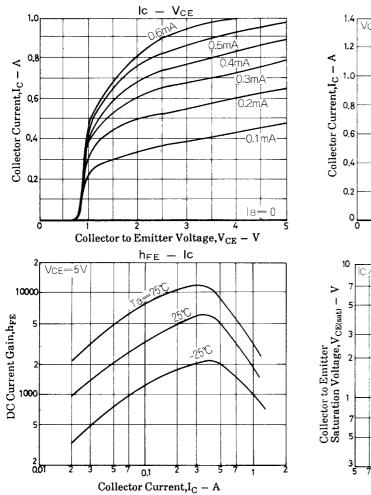


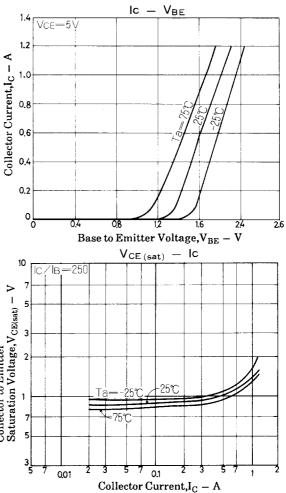
IC=250IB1=-250IB2=500mA

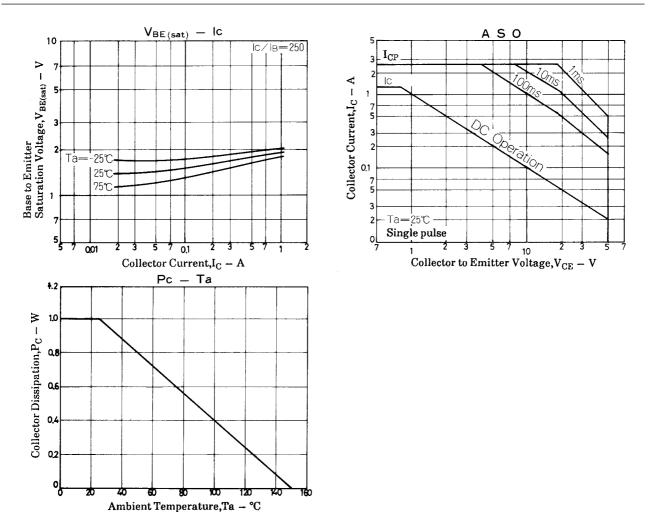
Es/b Test Circuit



Unit (resistance : Ω , capacitance : F)







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